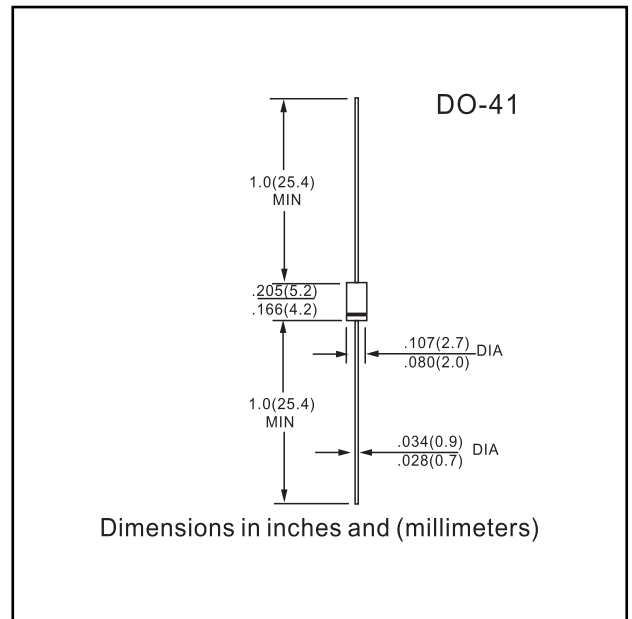


## FEATURES

- Metal-Semiconductor junction with guard ring
- Epitaxial construction
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

## MECHANICAL DATA

- Case : JEDEC DO-41 molded plastic
- Polarity : Color band denotes cathode
- Weight : 1.071grams
- Mounting position : Any



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
Single phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%

PARAMETER	SYMBOL	SB 120	SB 130	SB 140	SB 150	SB 160	SB 180	SB 1100	SB 1150	SB 1200	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	$V_{RMS}$	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	$V_{DC}$	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current	$I_F$	1.0									A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	30.0									A
Maximum Instantaneous Forward Voltage @ 1.0A	$V_F$	0.50		0.70		0.85		0.87	0.90		V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=100^\circ\text{C}$	$I_R$	0.5				0.2				mA	
		10.0				2.0					
Typical Junction Capacitance	$C_j$	70		50		40		30		pF	
Typical Thermal Resistance	$R_{\theta JA}$	70									°C/W
Operating Temperature Range	$T_J$	-55 to +125									°C
Storage Temperature Range	$T_{STG}$	-55 to +150									°C

# SCHOTTKY BARRIER RECTIFIERS

SB120 THRU SB1200  
20V-200V 1.0A

## RATINGS AND CHARACTERISTIC CURVES SB120 THRU SB1200

FIG. 1-TYPICAL FORWARD CURRENT DERATING CURVE

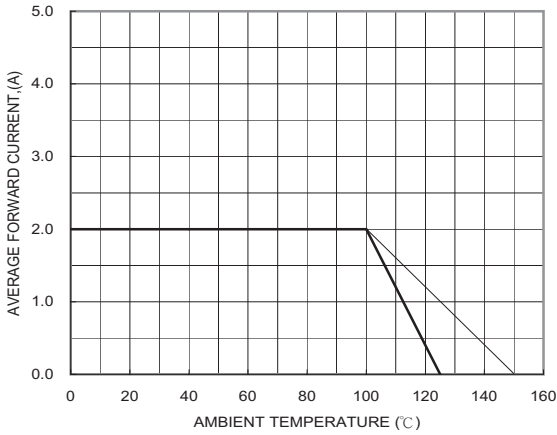


FIG. 2-TYPICAL FORWARD CHARACTERISTICS

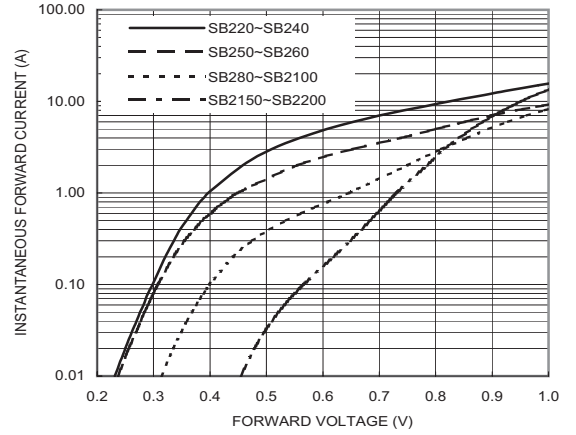


FIG. 3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

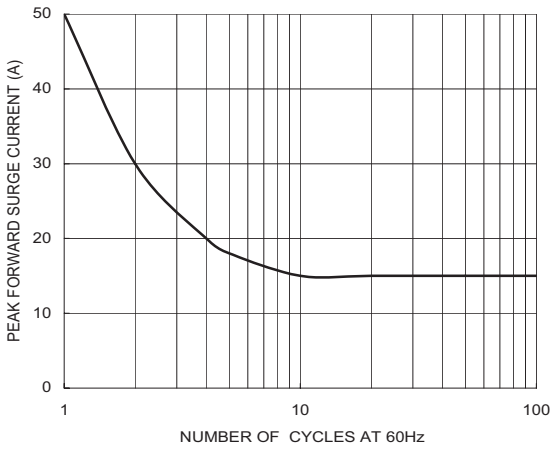


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

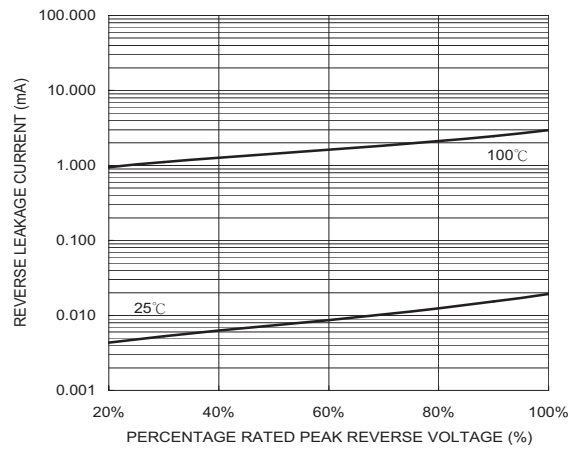


FIG. 5-TYPICAL JUNCTION CAPACITANCE

